# NSN 5961-01-111-4724

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## **Inclosure Material:**

Metal

**Overall Length:** 

1.572 inches

## **Overall Height:**

Between 0.250 inches and 0.450 inches

## **Overall Width:**

1.050 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

# Electrode Internally-electrically Connected To Case:

Collector

## Mounting Method:

Unthreaded hole

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

400.0 collector to base voltage, dc and 300.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc

# **Current Rating Per Characteristic:**

Between 10.00 amperes source cutoff current and 40.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

200.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## Test Data Document:

81755-c8646 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

1 case and 2 pin

## Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

No

Fiig:

A110a0